

**Introduction to Time - Varying Electrical Networks**  
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**Lecture 25**  
**Noise Factor Examples**

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Output noise is  $v_o^2$

$v_o^2 > v_s^2$        $\frac{v_o^2}{v_s^2} \geq 1$        $\left. \begin{array}{l} \text{Quantifies the} \\ \text{SNR degradation caused by} \\ \text{the amplifier} \end{array} \right\}$

$10 \log_{10}(NF) = \text{Noise figure (in dB)}$

$NF = \frac{4kT(R_s || R_p)}{4kT R_s \left(\frac{R_p}{R_s + R_p}\right)^2} = \frac{R_p R_s}{(R_s + R_p) R_p^2 \frac{R_s + R_p}{(R_s + R_p)^2}}$

Assume  $R_p = R_s$

$NF = \frac{4kT(R_s || R_s)}{4kT R_s \left(\frac{R_p}{R_s + R_p}\right)^2} = \frac{1}{\frac{R_p}{R_s + R_p}}$

$NF = 1 + \frac{R_s}{R_p}$

So, let us do some quick examples to help you figure out what the noise factor is? So, let us say this our source, this is  $R_s$ . And this is within quotes are blackbox. And I am going to say, oh well my blackbox simply has got a resistor  $R_p$ . Now, what comment can we make about the noise factor? What do we do?

We need to find the output noise. And we need to find the output noise assuming the box itself is noiseless. So, what is the output noise spectral density, what is the output voltage noise spectral density? It is  $4 kT$  times, pardon? Why  $R_p$  by  $R_p$  plus  $R_s$  is the whole square? It is simply, what is output noise voltage spectral density?  $4 kT R_p$  parallel  $R_s$ . Any confusion about this?

Now, you have to divide this by the output noise spectral density that would have resulted provided, which was noiseless?  $R_p$  was noiseless. Now, what would be the output noise spectral density? It is  $4 kT$  times, it is  $4 kT$  times  $R_s$  that is the noise spectral density of this resistor. And how, what is the transfer function from this noise source to the output?

$R_p$  by  $R_s$  plus  $R_p$ . So, why should I do this? The noise spectral density is going through within quotes again. So, we have to multiply by, again square and therefore this is nothing but the  $4 kT$  goes away, so this is  $R_p R_s$  divided by  $R_p$  plus  $R_s$  times  $R_s$  times  $R_p$  square by  $R_s$  plus  $R_p$  whole square.

And therefore, this goes away, this goes away, this goes away, this goes away, this goes away, this goes away. So, this is nothing but, the noise factor is nothing but  $1 + R_s$  over  $R_p$ . Sanity check. Well,  $R_p$  is infinity. What should we expect? Oh, well, you are not doing anything. So, presumably you are not losing SNR. So, I mean, sure enough, you get a noise factor of 1 or 0 dB.

And, and, I mean, well, we did not, I mean, we said this is our amplifier, so to speak, but what you are actually doing is that attenuating. So, if you simply attenuate with the resistive attenuator, as you can see, this is telling you that you are always going to be, I mean you are going to be degrading the SNR. And why does that make sense?

Student: ( ) (5:11)

Professor: Well, yeah, that is I mean, I guess that is right. So, what comment can you make about the absolute noise spectral density at the output has that. Let us assume, let us assume for argument's sake that  $R_s$  is equal to,  $R_p$  is made equal to  $R_s$ . So, what comment can we make about the noise spectral density of the output when compared to  $R_p$  equal to infinity? It is what comment can we make about the output noise spectral density if  $R_p$  is equal to  $R_s$ ?

It is  $4 kT$  times  $R_s$  by 2, so the noise spectral density at the output has actually gone down that does not mean that the signal is becoming any, I mean the signal to noise ratio is improving.

Why? Oh well, the signal is also attenuated by the same factor which basically means the signal power has gone down by, right, noise has gone down by half, but the signal power has gone down by a factor of 1/4, by a factor of 4.

So, the SNR has gone down by a factor of, the noise power has gone down by a factor of 2, signal power has gone down by a factor of 4. What comment can we make about the SNR? The SNR has actually gone down by a factor of 2, even though the noise floor has actually reduced by a factor.

And that is also, that is what the equation is telling us. If  $R_s$  is equal to  $R_p$ , then the noise factor is 2 which means the output SNR is lower than the input SNR by a factor of 2. The noise factor does not say anything about the absolute noise flow. It is only quantifying how badly you have done with respect to 2 SNR. Let us do another example.


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Now, let us take a transistor and at low frequency what comment can we make about, what is the small signal equivalent of the transistor? It is nothing but this is the incremental  $V_{GS}$ , this is  $g_m$  times  $v_{gs}$ , this is  $r_o$  and as I mentioned, the transistor is accompanied by a noise source whose spectral density is for the long channel MOS transistor can be shown to be  $8 kT$  over  $3$  times  $g_m$  but then a long channel MOS transistors only exist in the textbooks. So, what better formula is to use  $4 kT \eta$  times  $g_m$ ,  $\eta$  is some number that fits measurements,  $\eta$  or  $\gamma$  or whatever they are, they have some, that is the usual non ideality factor.

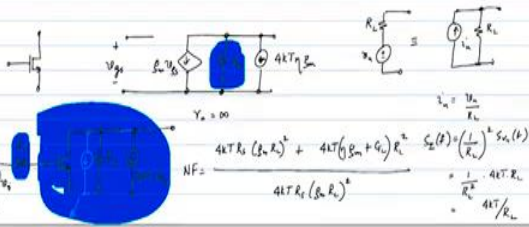
Ideally, eta should be 2 thirds. In reality, it is more like 3 halves. So, whatever I mean, the designer has no control over what you get, it is what you get. And so, another thing I like to point out is that even though you have  $r_o$  which models the finite nonzero lambda of the device is not a physical resistance. And therefore, there is no noise, so that current source is not the noise associated with, it is not noise associated with that  $r_o$ .

And, so this is a simple model for noise. In fact, it turns out that in reality, there is also another noise source in the gate, but that only becomes, shows up at really high frequency. But for most calculations, at least at low frequencies, this is good enough.

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Assume  $R_p = R_s$



$$NF = \frac{4kT R_s (\beta_m R_o)^2 + 4kT (\beta_m + G_m) R_o^2}{4kT R_s (\beta_m R_o)^2} \cdot S_v(f) \cdot \left(\frac{1}{R_o}\right)^2 S_{i_n}(f)$$

$$= \frac{1}{R_o^2} \cdot \frac{4kT R_o}{4kT / R_o}$$

$$NF = 1 + \frac{(\beta_m + G_m) R_o^2}{R_s \beta_m^2 R_o^2}$$

4kT\*gamma\*beta\_m

NPTEL

Handwritten notes on a whiteboard showing circuit diagrams and noise factor equations for a common source amplifier. The diagrams include a transistor model with noise sources and an equivalent circuit. The equations derive the noise factor  $NF = 1 + \frac{(\gamma g_m + G_c)}{R_s g_m^2}$  and a boxed version  $NF = 1 + \frac{\gamma}{g_m R_s} + \frac{1}{(R_s R_i)(g_m R_i)}$ .

Now, let us do a simple common source amplifier whose incremental picture is shown here. And this is  $V_i$ , this is  $R_s$ , and that is  $R_L$ . So, what comment can we make? How do we, what is the noise factor? What do we do? First thing is to find the total output noise. So, what will be the total output noise, noise spectral density?

Well, what is the gain from  $R_s$  to the output, the voltage source in series with  $R_s$  to the output? Well, let us assume again, let us make life simple and assume that  $r_o$  is equal to infinity. So, what is the gain from the noise source to the output? Minus  $g_m R_L$ , So, what would be the output noise spectral density due to  $R_s$ ? It is  $4 kT R_s$  times  $g_m R_L$  minus  $g_m R_L$  the whole square which is the same as plus  $g_m R_L$  the whole square. Plus, what else? Is that all?

How many noise sources are there? The main thing here is the transistor man. Huh? How many noise sources do we have? 3 noise sources. Now, I mean with, even I mean, of course, the 3 noise sources we can say we can all do this in our minds, but you can imagine what will happen if you have 50 transistors like this and there is tons of noise sources, and there is 1 output, and you need to now calculate, and I made our life simple by assuming  $r_o$  is infinity and there is no parasitic capacitances, etc.

In reality, all that stuff is going to come in and then it is going to be a mess. So, that is where the adjoint is, the inter reciprocal network is so useful, because you write down the  $(\cdot)$ (11:50) equations of this big network, you solve it once, and you get all the transfer functions that you are looking for.

So, back to our example. So, there are 3 noise sources. Fortunately, it seems like we can use some simple trick to convert that into 2. So, this noise source is that of the transistor and it has  $4 kT \eta g_m$ , the noise source of the resistor is a voltage source. But we know how to convert from not an equivalent to a  $(12:32)$  equivalent.

So,  $V_n$  in series with  $R_L$  is equivalent to in parallel with  $R_L$ . And what is  $i_n$ ?  $v_n$  by  $R_L$ . So, the noise spectral density of the current source is nothing but well, you are multiplying that current by  $1$  by  $R_L$  times  $v_n$ . So, you multiply this by a constant so you have to I mean, you multiply that by  $1$  by  $R_L$  square times  $S_{v_n}$  of  $F$  which is nothing but  $1$  over  $R_L$  square times  $4 kT R_L$ , so this is nothing but  $4 kT$  over  $R_L$ , makes sense guys.

So, we have 2 noise sources here, one which corresponds to the transistor, one that corresponds to  $4 kT G_L$ . So, what is the total noise at the output therefore? This is the input source plus what is the total noise voltage at the output now? Yes, Danish?  $4 kT \eta g_m$  plus  $G_L$  that is the current flows into  $R_L$ . So, what should I, what should I do here?  $R_L$  square, this is the total noise at the output of the amplifier, and you have to divide this by the noise that you would have got if the amplifier itself was noiseless.

So, in other words, everything inside this blue box, if it was noiseless what is the noise you would have gone? What would you have got that is easy to do is simply  $4 kT R_s$  times  $g_m R_L$ . So, this is the noise factor and therefore, the noise factor is  $1$  plus  $\eta g_m$  plus  $G_L$  into  $R_L$  square divided by  $R_s$  times  $g_m$  square  $R_L$  square.

And so, this goes away, this goes away and you have  $1$  plus  $\eta$  over  $g_m R_s$  plus  $1$  over  $g_m R_s$  times  $g_m R$ . Now, why does this make intuitive sense? Or is there a sanity check? Well, if  $R_L$  was noiseless, the noise factor would be  $1$  plus  $\eta$  over  $g_m R_s$ . Now, what comment can we make about the noise spectral density added by the resistor in relation to that added by the transistor?

Actually, we missed, no I think we are okay. So, what comment can we add? Yeah, so basically, when you refer, I mean adding a noise current here is equivalent I mean, what disturbance at this node would cause a disturbance of  $4 kT$ , I mean, in other words, what disturbance must I add here at the gate to cause a current  $i$  in the drain?

Whatever disturbance there is in the drain current that has to be divided down by  $g_m$  in order to. And so, if you are looking at the output voltage, this current will cause, we will have a gain of only  $R_L$  whereas the voltage here will have an effect of  $g_m$  times  $R_L$ . So, you can see that the noise added by the resistor is I mean  $R_L$  is lot less important than the noise added by the transistor, because if you choose a large gain  $g_m R_L$  is a large number. Basically, it is saying that the noise added by the resistor, noise current added by the resistor, load resistor is much smaller than the noise current added by the transistor itself.

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The next thing I am going to do another example, but I am not going to go through the algebra, I will leave you to do the algebra but I am going to what, I would like to discuss intuitively what we should expect. So, this is a 2-stage amplifier is  $g_m 1, R 1, g_m 2 R 2$ . And so, which, I mean based on our experience so far, which, what do you think? I mean which are the noise sources do you think is the most, contributes the most to the noise figure?

$g_m$ ?  $g_m 1$ . Why? Intuitively why does it make sense? Oh well yeah, that is, that is right I mean any, the noise source, any noise added by the transistor the noise current is now convert into voltage that is further amplified. So, a lot of the noise here will be due to  $g_m 1$  and  $R_s$ . And as you keep going further down the chain, let us say we have a long cascade, the noise figure is going to be, if you have a cascade of amplifiers, each 1 which is amplifying the signal, and of

course, also amplifying noise from preceding stages, which of these stages will be the most, which of the stages would you expect is the most critical as far as the noise is concerned?

The first stage. And which do you think, as you keep traveling down the chain, the signal is getting bigger and bigger. So, which would you worry about distorting the signal a lot? Well, yeah, the last stages are the ones which you should be primarily worried about as far as distortion is concerned. And the first stages are the ones that you should be worried about, primarily about noise. And that is how it goes.

So, that is all I had to say regarding noise factor and noise figure. And you should be in a, I mean and again, I would like to remind you that so far, we have just discussed circuits where there is no memory so that the algebra becomes easier on the blackboard, in reality all these transfer functions will have, there will be frequency dependence of all these gains and stuff like that. So basically, wherever you see a gain, you replace it with a transfer function. And therefore, in general noise factor is a function of, it is a function of frequency because gain is a function of frequency. So, that basically is all I had to say about noise factor.